TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT process)

2SA1586

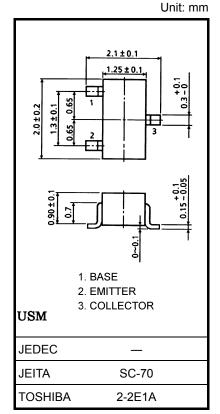
Audio Frequency General Purpose Amplifier Applications

- High voltage and high current: $V_{CEO} = -50$ V, $I_C = -150$ mA (max)
- Excellent hFE linearity: hFE (I_C = -0.1 mA)/ hFE (I_C = -2 mA)
 - = 0.95 (typ.)
- High h_{FE} : $h_{FE} = 70 \sim 400$
- Low noise: NF = 1dB (typ.), 10dB (max)
- Complementary to 2SC4116
- Small package

Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit	
Collector-base voltage	V _{CBO}	-50	V	
Collector-emitter voltage	V _{CEO}	-50	V	
Emitter-base voltage	V _{EBO}	-5	V	
Collector current	ΙC	-150	mA	
Base current	Ι _Β	-30	mA	
Collector power dissipation	PC	100	mW	
Junction temperature	Tj	125	°C	
Storage temperature range	T _{stg}	-55~125	°C	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.



Weight: 0.006 g (typ.)

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

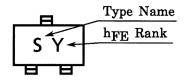
Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I _{CBO}	$V_{CB} = -50 \text{ V}, \text{ I}_E = 0$	_	_	-0.1	μA
Emitter cut-off current	I _{EBO}	$V_{EB} = -5 \text{ V}, \text{ I}_{C} = 0$	_	_	-0.1	μA
DC current gain	h _{FE} (Note)	$V_{CE} = -6 \text{ V}, \text{ I}_{C} = -2 \text{ mA}$	70	_	400	
Collector-emitter saturation voltage	V _{CE (sat)}	$I_{C} = -100 \text{ mA}, I_{B} = -10 \text{ mA}$	_	-0.1	-0.3	V
Transition frequency	f _T	$V_{CE} = -10 \text{ V}, I_{C} = -1 \text{ mA}$	80	_		MHz
Collector output capacitance	C _{ob}	$V_{CB} = -10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$	_	4	7	pF
Noise figure	NF	V_{CE} = –6 V, I_{C} = –0.1 mA, f = 1 kHz, Rg = 10 k Ω		1.0	10	dB

Note: hFE classification O (O): 70~140, Y (Y): 120~240, GR (G): 200~400

() marking symbol

Marking



TOSHIBA

-1.2

-1.0

- 25

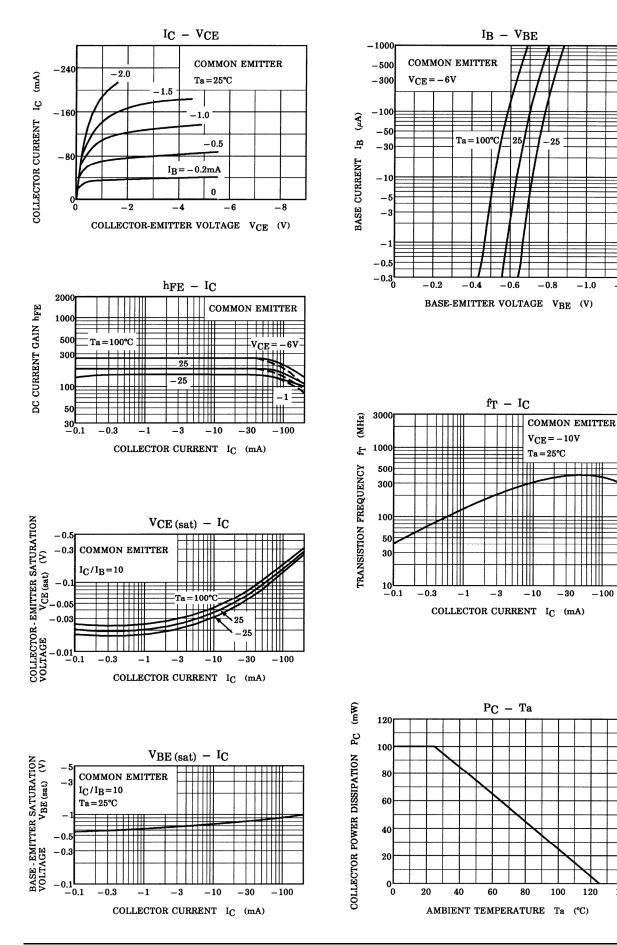
-0.8

-30

100

120

-100



140

RESTRICTIONS ON PRODUCT USE

20070701-EN GENERAL

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- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property.
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